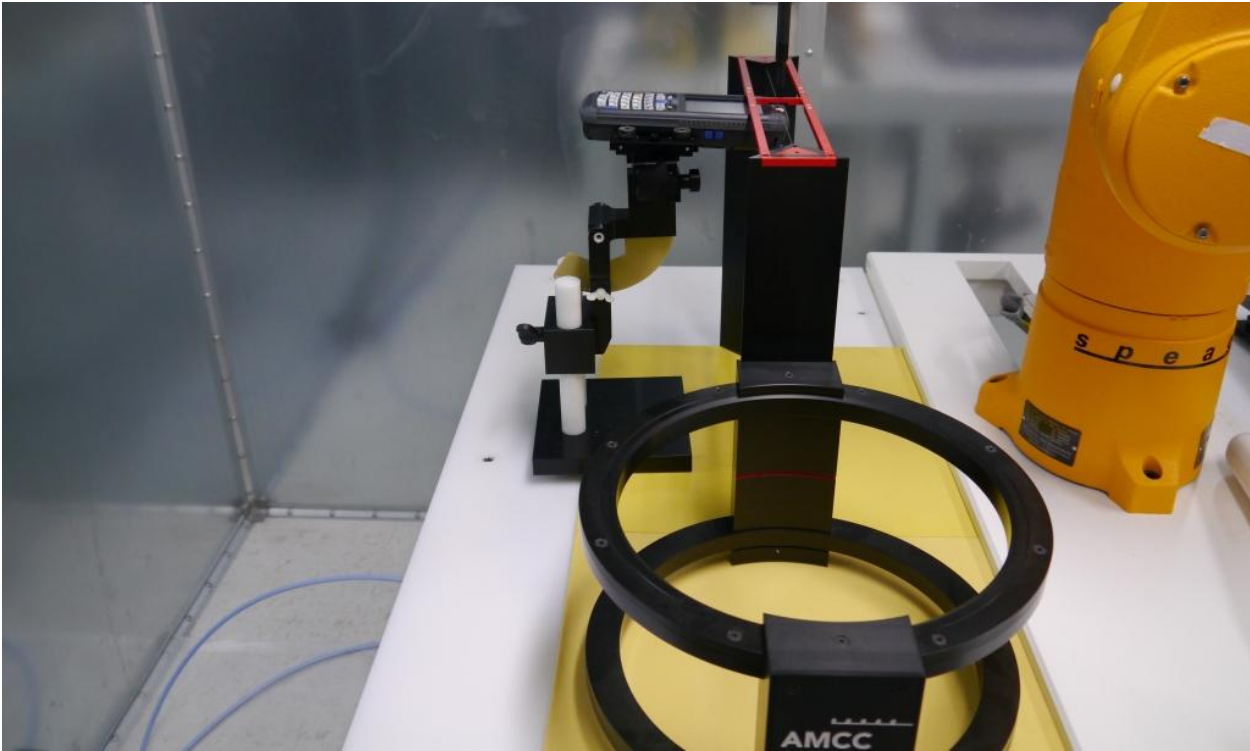


HAC Annex Report

Table of Contents

1	SETUP PHOTOGRAPHS.....	2
2	SYSTEM VALIDATION REPORTS.....	3
	HAC RF E-Field System Check.....	3
	HAC RF E-Field System Check.....	5
3	HAC RF EMISSIONS TEST PLOTS.....	7

1 SETUP PHOTOGRAPHS



2 SYSTEM VALIDATION REPORTS

Date/Time: 12/11/2014 8:17:16 AM

Test Laboratory: SGS North America

HAC RF E-Field System Check

DUT: HAC-Dipole 835 MHz; Type: D835V3; Serial: 1060

Communication System: UID 0, CW; Communication System Band: ITD835 (835.0 MHz); Frequency: 835 MHz; Communication System PAR: 0 dB; PMF: 1

Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY Configuration:

- Probe: ER3DV6 - SN2308; ConvF(1, 1, 1); Calibrated: 1/17/2014;
- Sensor-Surface: (Fix Surface), $z = 9.7$
- Electronics: DAE4 Sn1287; Calibrated: 10/4/2011
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: NA
- DASYS 52.8.8(1222); SEMCAD X 14.6.10(7331)

Dipole E-Field measurement (E-field scan for ANSI C63.19-2011 compliance)/E Scan - measurement distance from the probe sensor center to CD835 = 10mm &

15mm/Hearing Aid Compatibility Test at 15mm distance (41x361x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 126.7 V/m; Power Drift = -0.19 dB

PMR not calibrated. PMF = 1.000 is applied.

E-field emissions = 102.2 V/m

Near-field category: M4 (AWF 0 dB)

PMF scaled E-field

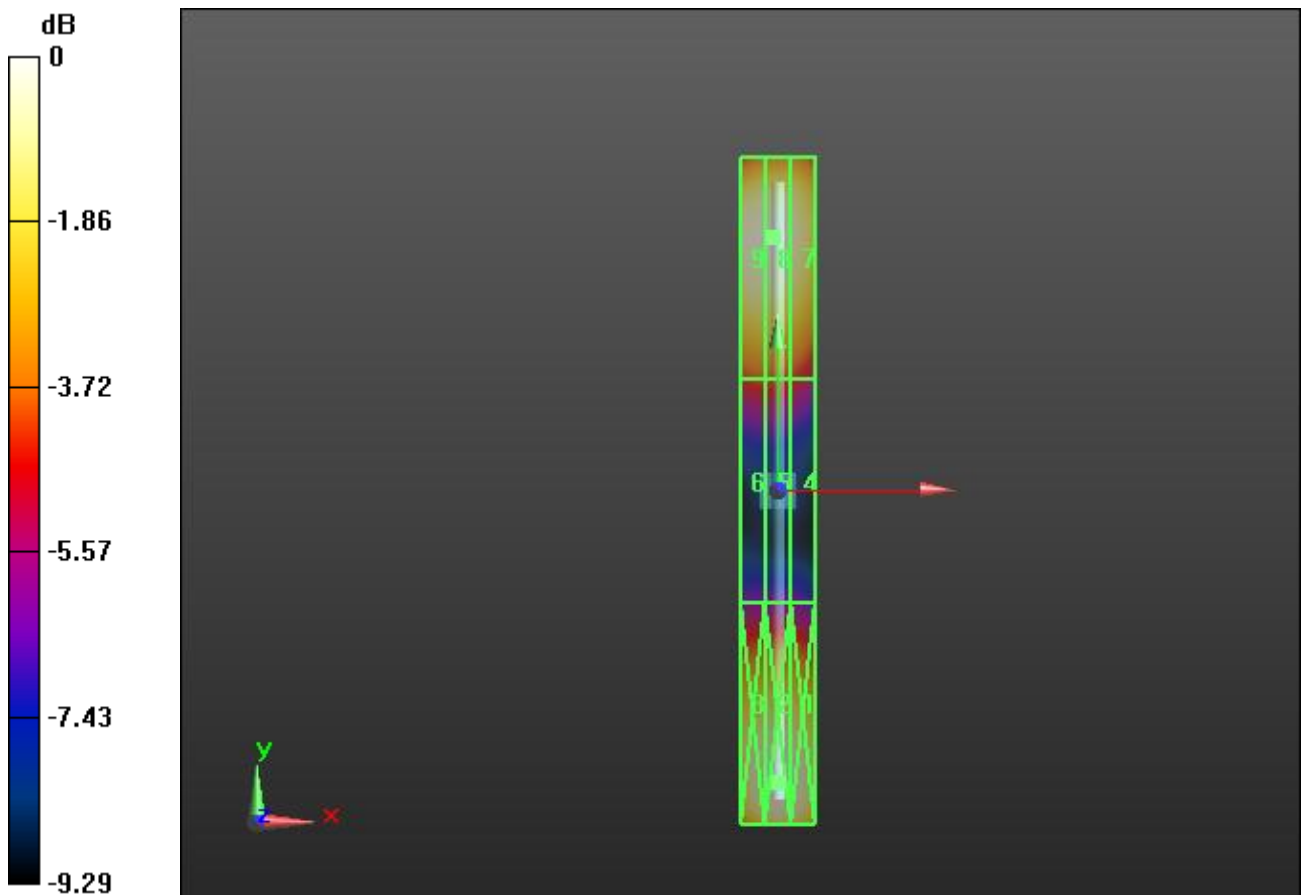
Grid 1 M4 101.5 V/m	Grid 2 M4 103.3 V/m	Grid 3 M4 99.64 V/m
Grid 4 M4 62.44 V/m	Grid 5 M4 64.60 V/m	Grid 6 M4 64.60 V/m
Grid 7 M4 97.67 V/m	Grid 8 M4 102.2 V/m	Grid 9 M4 101.8 V/m

Cursor:

Total = 103.3 V/m

E Category: M4

Location: 0.5, -78.5, 9.7 mm



0 dB = 103.3 V/m = 40.28 dBV/m

Date/Time: 12/11/2014 9:57:00 AM

Test Laboratory: SGS North America

HAC RF E-Field System Check

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1047

Communication System: UID 0, CW; Communication System Band: CD1880 (1880.0 MHz);

Frequency: 1880 MHz; Communication System PAR: 0 dB; PMF: 1

Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY Configuration:

- Probe: ER3DV6 - SN2308; ConvF(1, 1, 1); Calibrated: 1/17/2014;
- Sensor-Surface: (Fix Surface), z = 9.7
- Electronics: DAE4 Sn1287; Calibrated: 10/4/2011
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: NA
- DASYS2 52.8.8(1222); SEMCAD X 14.6.10(7331)

Dipole E-Field measurement (E-field scan for ANSI C63.19-2011 compliance)/E Scan - measurement distance from the probe sensor center to CD1880 = 10mm & 15mm/Hearing Aid Compatibility Test at 15mm distance (41x181x1): Interpolated grid:

dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 135.1 V/m; Power Drift = 0.10 dB

PMR not calibrated. PMF = 1.000 is applied.

E-field emissions = 84.53 V/m

Near-field category: M3 (AWF 0 dB)

PMF scaled E-field

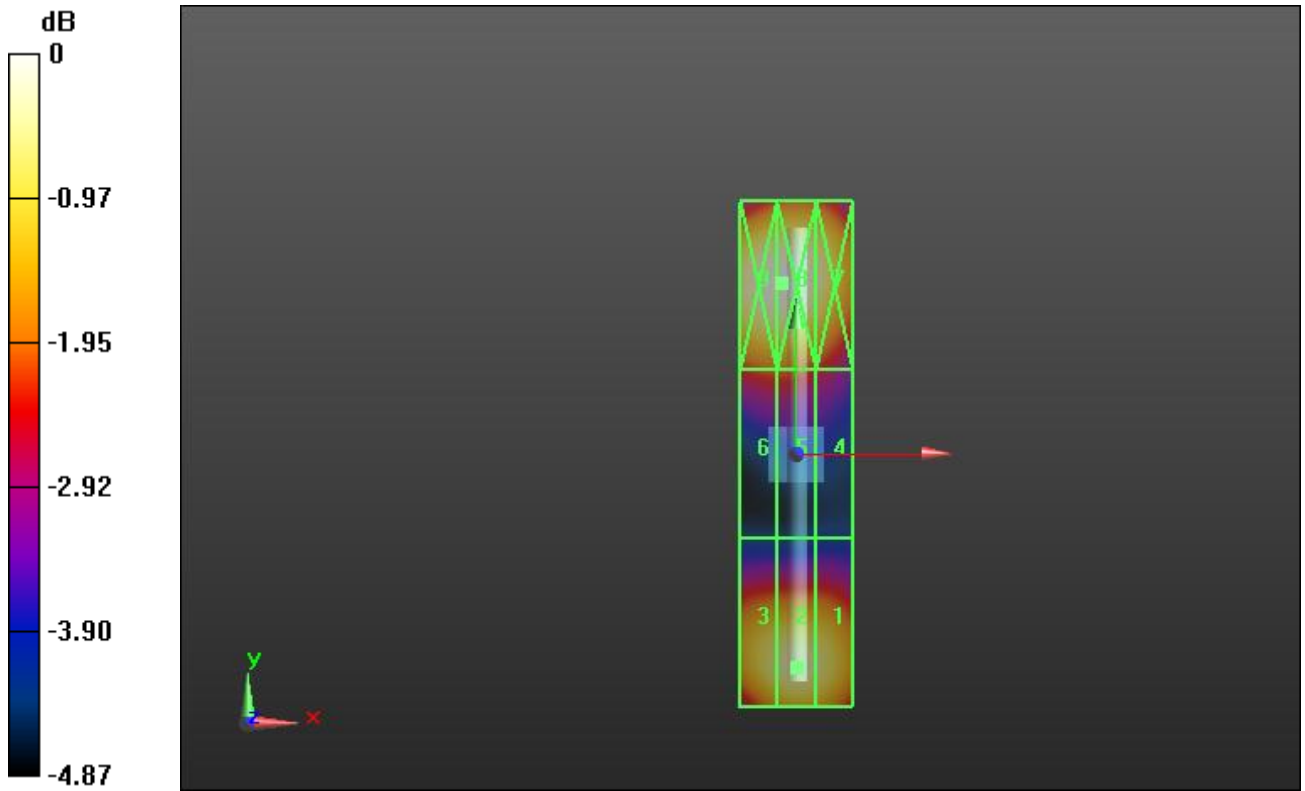
Grid 1 M3 83.06 V/m	Grid 2 M3 84.53 V/m	Grid 3 M3 82.76 V/m
Grid 4 M3 66.97 V/m	Grid 5 M3 70.06 V/m	Grid 6 M3 70.03 V/m
Grid 7 M3 84.16 V/m	Grid 8 M3 88.22 V/m	Grid 9 M3 88.19 V/m

Cursor:

Total = 88.22 V/m

E Category: M3

Location: -2.5, 30.5, 9.7 mm



0 dB = 88.22 V/m = 38.91 dBV/m

3 HAC RF EMISSIONS TEST PLOTS

Scan C1

Date/Time: 12/11/2014 9:30:19 AM

Test Laboratory: SGS North America

DUT: Intermec CN70e; Type: Handheld PC; Serial: NA

Communication System: UID 10039 - CAB, CDMA2000 (1xRTT, RC1); Communication System Band: Band Class 0 (815.0 - 849.0 MHz); Frequency: 824.7 MHz; Communication System PAR: 4.57 dB; PMF: 1.03157

Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY Configuration:

- Probe: ER3DV6 - SN2308; ConvF(1, 1, 1); Calibrated: 1/17/2014;
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE4 Sn1287; Calibrated: 10/4/2011
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: NA
- DASYS 52.8.8(1222); SEMCAD X 14.6.10(7331)

Device E-Field measurement (E-field scan for ANSI C63.19-2011 compliance)/E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 19.85 V/m; Power Drift = -0.04 dB

PMR calibrated. Calibrated PMF = 1.032 is applied.

E-field emissions = 55.04 V/m

Near-field category: M4 (AWF 0 dB)

PMF scaled E-field

Grid 1 M4 40.50 V/m	Grid 2 M4 33.71 V/m	Grid 3 M4 30.95 V/m
Grid 4 M4 36.80 V/m	Grid 5 M4 55.04 V/m	Grid 6 M4 23.01 V/m
Grid 7 M4 54.45 V/m	Grid 8 M4 31.05 V/m	Grid 9 M4 44.90 V/m

Category	AWF (dB)	Limits for E-Field Emissions (V/m) > 960MHz	Limits for H-Field Emissions (A/m) > 960MHz
----------	----------	---	---

M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.14 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.14

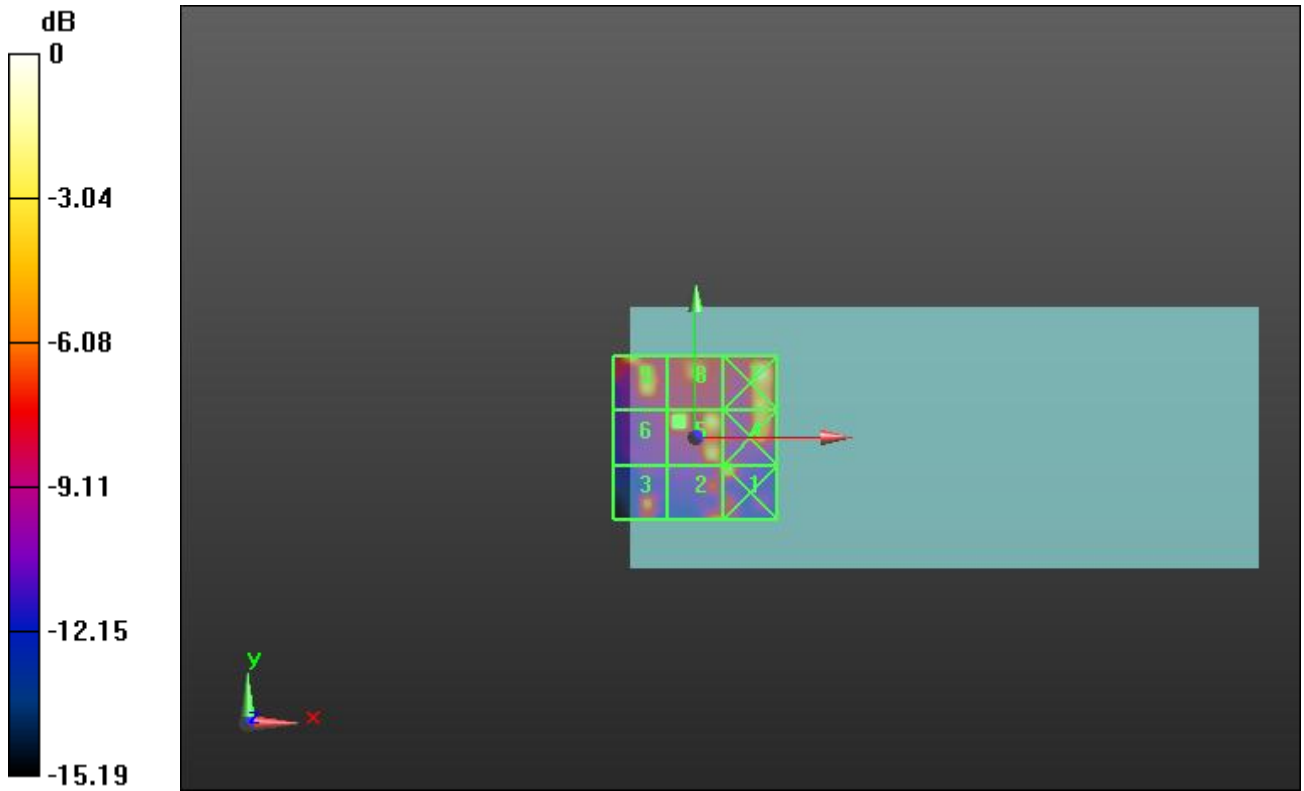
Category	AWF (dB)	Limits for E-Field Emissions (V/m) < 960MHz	Limits for H-Field Emissions (A/m) < 960 MHz
M1	0	631 - 1122	1.91 - 3.39
	-5	473.2 - 841.4	1.43 - 2.54
M2	0	354.8 - 631	1.07 - 1.91
	-5	266.1 - 473.2	0.8 - 1.43
M3	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M4	0	<199.5	<0.6
	-5	<149.6	<0.45

Cursor:

Total = 55.04 V/m

E Category: M4

Location: -5, 5, 8.7 mm



0 dB = 55.04 V/m = 34.81 dBV/m

Scan C2

Date/Time: 12/11/2014 9:09:40 AM

Test Laboratory: SGS North America

DUT: Intermec CN70e; Type: Handheld PC; Serial: NA

Communication System: UID 10039 - CAB, CDMA2000 (1xRTT, RC1); Communication System Band: Band Class 0 (815.0 - 849.0 MHz); Frequency: 836.52 MHz; Communication System PAR: 4.57 dB; PMF: 1.03157

Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY Configuration:

- Probe: ER3DV6 - SN2308; ConvF(1, 1, 1); Calibrated: 1/17/2014;
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE4 Sn1287; Calibrated: 10/4/2011
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: NA
- DASY52 52.8.8(1222); SEMCAD X 14.6.10(7331)

Device E-Field measurement (E-field scan for ANSI C63.19-2011 compliance)/E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 23.81 V/m; Power Drift = -0.30 dB

PMR calibrated. Calibrated PMF = 1.032 is applied.

E-field emissions = 54.41 V/m

Near-field category: M4 (AWF 0 dB)

PMF scaled E-field

Grid 1 M4 19.65 V/m	Grid 2 M4 38.19 V/m	Grid 3 M4 16.28 V/m
Grid 4 M4 23.68 V/m	Grid 5 M4 54.41 V/m	Grid 6 M4 31.93 V/m
Grid 7 M4 25.80 V/m	Grid 8 M4 59.56 V/m	Grid 9 M4 41.92 V/m

Category	AWF (dB)	Limits for E-Field Emissions (V/m) > 960MHz	Limits for H-Field Emissions (A/m) > 960MHz
----------	----------	---	---

M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.14 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.14

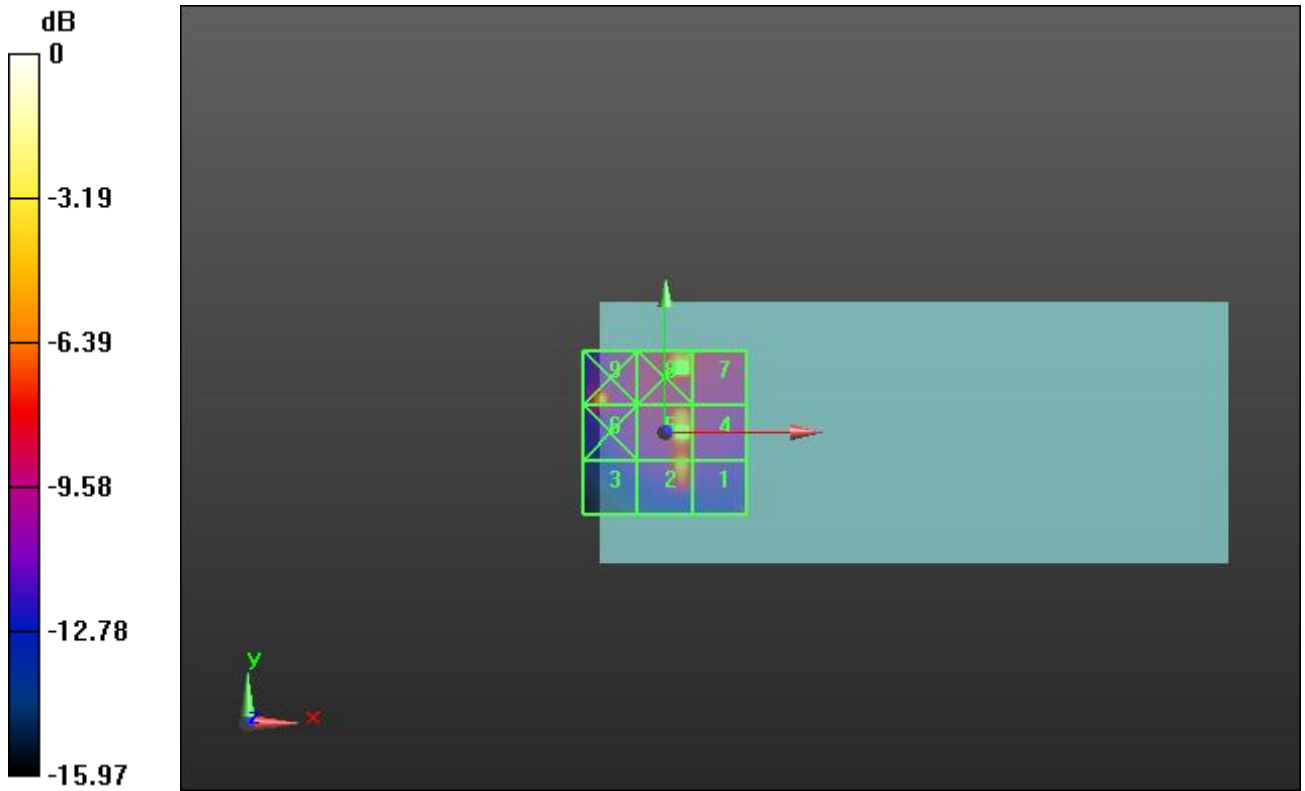
Category	AWF (dB)	Limits for E-Field Emissions (V/m) < 960MHz	Limits for H-Field Emissions (A/m) < 960 MHz
M1	0	631 - 1122	1.91 - 3.39
	-5	473.2 - 841.4	1.43 - 2.54
M2	0	354.8 - 631	1.07 - 1.91
	-5	266.1 - 473.2	0.8 - 1.43
M3	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M4	0	<199.5	<0.6
	-5	<149.6	<0.45

Cursor:

Total = 59.56 V/m

E Category: M4

Location: 5, 20, 8.7 mm



0 dB = 59.56 V/m = 35.50 dBV/m

Test Laboratory: SGS North America

DUT: Intermec CN70e; Type: Handheld PC; Serial: NA

Communication System: UID 10039 - CAB, CDMA2000 (1xRTT, RC1); Communication System Band: Band Class 0 (815.0 - 849.0 MHz); Frequency: 848.31 MHz; Communication System PAR: 4.57 dB; PMF: 1.03157

Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY Configuration:

- Probe: ER3DV6 - SN2308; ConvF(1, 1, 1); Calibrated: 1/17/2014;
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE4 Sn1287; Calibrated: 10/4/2011
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: NA
- DASYS 52.8.8(1222); SEMCAD X 14.6.10(7331)

Device E-Field measurement (E-field scan for ANSI C63.19-2011 compliance)/E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 24.59 V/m; Power Drift = -0.05 dB

PMR calibrated. Calibrated PMF = 1.032 is applied.

E-field emissions = 19.60 V/m

Near-field category: M4 (AWF 0 dB)

PMF scaled E-field

Grid 1 M4 16.48 V/m	Grid 2 M4 16.46 V/m	Grid 3 M4 15.39 V/m
Grid 4 M4 17.36 V/m	Grid 5 M4 19.60 V/m	Grid 6 M4 18.75 V/m
Grid 7 M4 18.75 V/m	Grid 8 M4 19.30 V/m	Grid 9 M4 20.85 V/m

Category	AWF (dB)	Limits for E-Field Emissions (V/m) > 960MHz	Limits for H-Field Emissions (A/m) > 960MHz
M1	0	199.5 - 354.8	0.6 - 1.07

	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.14 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.14

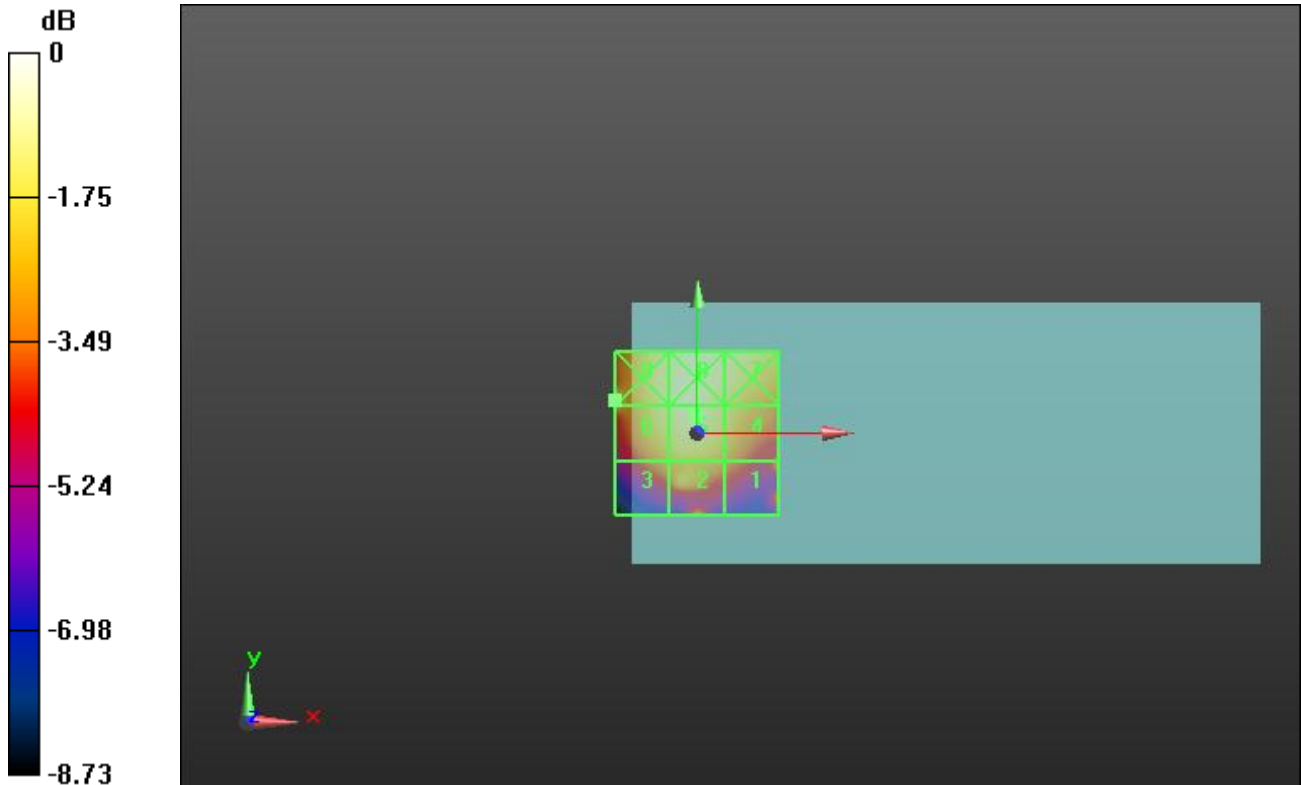
Category	AWF (dB)	Limits for E-Field Emissions (V/m) < 960MHz	Limits for H-Field Emissions (A/m) < 960 MHz
M1	0	631 - 1122	1.91 - 3.39
	-5	473.2 - 841.4	1.43 - 2.54
M2	0	354.8 - 631	1.07 - 1.91
	-5	266.1 - 473.2	0.8 - 1.43
M3	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M4	0	<199.5	<0.6
	-5	<149.6	<0.45

Cursor:

Total = 20.85 V/m

E Category: M4

Location: -25, 10, 8.7 mm



$$0 \text{ dB} = 20.85 \text{ V/m} = 26.38 \text{ dBV/m}$$

Test Laboratory: SGS North America

DUT: Intermec CN70e; Type: Handheld PC; Serial: NA

Communication System: UID 10039 - CAB, CDMA2000 (1xRTT, RC1); Communication System Band: Band Class 1 (1850.0 - 1910.0 MHz); Frequency: 1851.25 MHz; Communication System PAR: 4.57 dB; PMF: 1.03157

Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY Configuration:

- Probe: ER3DV6 - SN2308; ConvF(1, 1, 1); Calibrated: 1/17/2014;
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE4 Sn1287; Calibrated: 10/4/2011
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: NA
- DASYS 52.8.8(1222); SEMCAD X 14.6.10(7331)

Device E-Field measurement (E-field scan for ANSI C63.19-2011 compliance)/E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 28.49 V/m; Power Drift = 0.06 dB

PMR calibrated. Calibrated PMF = 1.032 is applied.

E-field emissions = 32.01 V/m

Near-field category: M4 (AWF 0 dB)

PMF scaled E-field

Grid 1 M4 34.70 V/m	Grid 2 M4 60.94 V/m	Grid 3 M4 33.17 V/m
Grid 4 M4 17.94 V/m	Grid 5 M4 32.01 V/m	Grid 6 M4 25.84 V/m
Grid 7 M4 10.26 V/m	Grid 8 M4 13.50 V/m	Grid 9 M4 15.89 V/m

Category	AWF (dB)	Limits for E-Field Emissions (V/m) > 960MHz	Limits for H-Field Emissions (A/m) > 960MHz
M1	0	199.5 - 354.8	0.6 - 1.07

	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.14 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.14

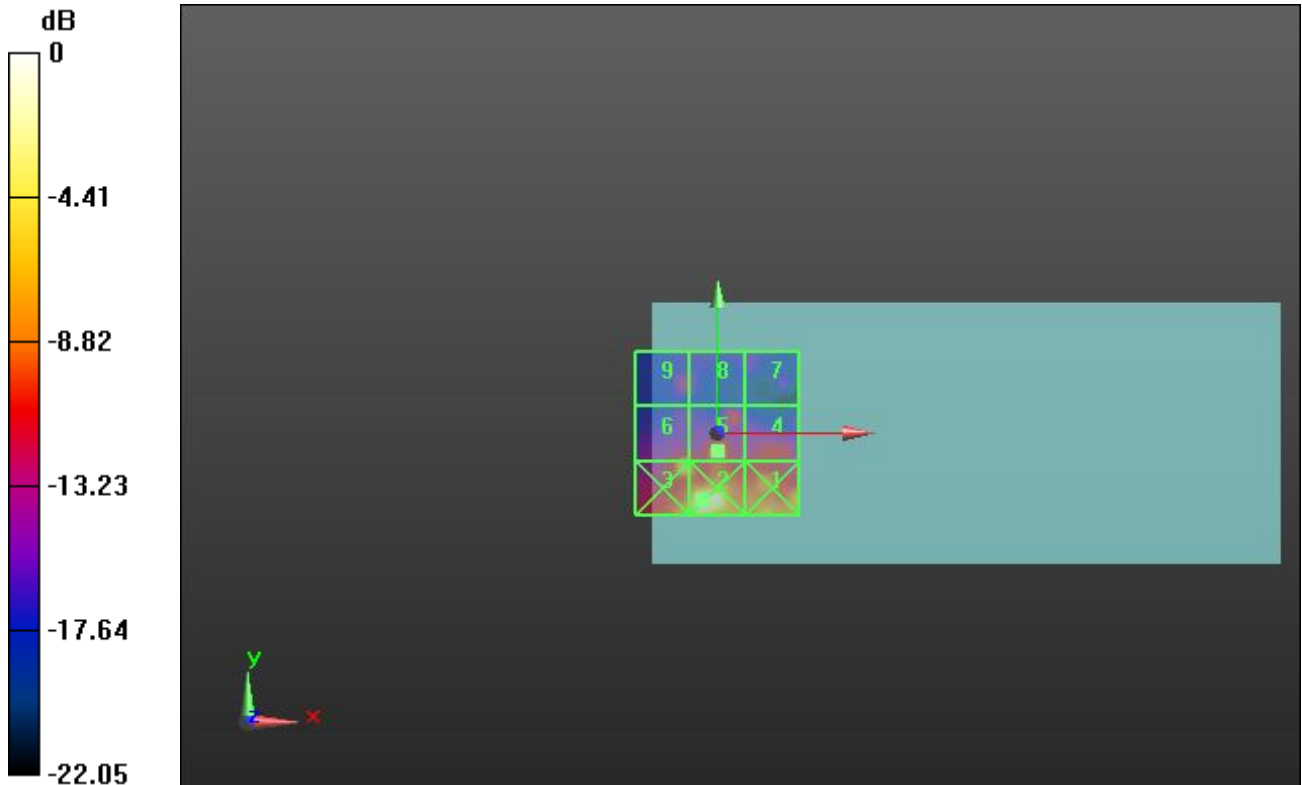
Category	AWF (dB)	Limits for E-Field Emissions (V/m) < 960MHz	Limits for H-Field Emissions (A/m) < 960 MHz
M1	0	631 - 1122	1.91 - 3.39
	-5	473.2 - 841.4	1.43 - 2.54
M2	0	354.8 - 631	1.07 - 1.91
	-5	266.1 - 473.2	0.8 - 1.43
M3	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M4	0	<199.5	<0.6
	-5	<149.6	<0.45

Cursor:

Total = 60.94 V/m

E Category: M4

Location: -4.5, -20.5, 8.7 mm



0 dB = 60.94 V/m = 35.70 dBV/m

Test Laboratory: SGS North America

DUT: Intermec CN70e; Type: Handheld PC; Serial: NA

Communication System: UID 10039 - CAB, CDMA2000 (1xRTT, RC1); Communication System Band: Band Class 1 (1850.0 - 1910.0 MHz); Frequency: 1880 MHz; Communication System PAR: 4.57 dB; PMF: 1.03157

Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY Configuration:

- Probe: ER3DV6 - SN2308; ConvF(1, 1, 1); Calibrated: 1/17/2014;
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE4 Sn1287; Calibrated: 10/4/2011
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: NA
- DASYS 52.8.8(1222); SEMCAD X 14.6.10(7331)

Device E-Field measurement (E-field scan for ANSI C63.19-2011 compliance)/E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 18.11 V/m; Power Drift = 0.10 dB

PMR calibrated. Calibrated PMF = 1.032 is applied.

E-field emissions = 18.68 V/m

Near-field category: M4 (AWF 0 dB)

PMF scaled E-field

Grid 1 M4 35.04 V/m	Grid 2 M4 31.78 V/m	Grid 3 M4 19.84 V/m
Grid 4 M4 16.04 V/m	Grid 5 M4 18.68 V/m	Grid 6 M4 13.10 V/m
Grid 7 M4 8.177 V/m	Grid 8 M4 11.16 V/m	Grid 9 M4 14.26 V/m

Category	AWF (dB)	Limits for E-Field Emissions (V/m) > 960MHz	Limits for H-Field Emissions (A/m) > 960MHz
M1	0	199.5 - 354.8	0.6 - 1.07

	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.14 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.14

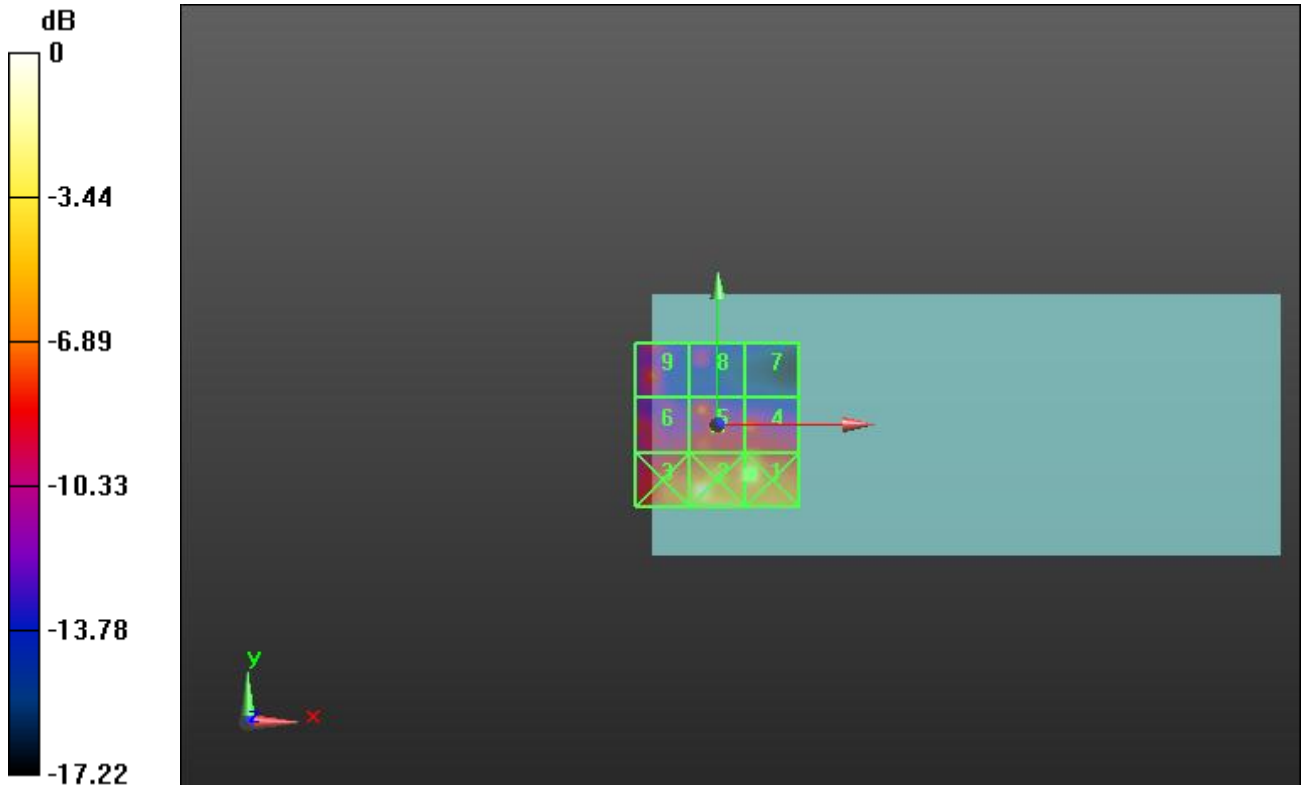
Category	AWF (dB)	Limits for E-Field Emissions (V/m) < 960MHz	Limits for H-Field Emissions (A/m) < 960 MHz
M1	0	631 - 1122	1.91 - 3.39
	-5	473.2 - 841.4	1.43 - 2.54
M2	0	354.8 - 631	1.07 - 1.91
	-5	266.1 - 473.2	0.8 - 1.43
M3	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M4	0	<199.5	<0.6
	-5	<149.6	<0.45

Cursor:

Total = 35.04 V/m

E Category: M4

Location: 10, -15, 8.7 mm



0 dB = 35.04 V/m = 30.89 dBV/m

Test Laboratory: SGS North America

DUT: Intermec CN70e; Type: Handheld PC; Serial: NA

Communication System: UID 10039 - CAB, CDMA2000 (1xRTT, RC1); Communication System Band: Band Class 1 (1850.0 - 1910.0 MHz); Frequency: 1908.75 MHz; Communication System PAR: 4.57 dB; PMF: 1.03157

Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASYS (IEEE/IEC/ANSI C63.19-2007)

DASY Configuration:

- Probe: ER3DV6 - SN2308; ConvF(1, 1, 1); Calibrated: 1/17/2014;
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE4 Sn1287; Calibrated: 10/4/2011
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: NA
- DASYS 52.8.8(1222); SEMCAD X 14.6.10(7331)

Device E-Field measurement (E-field scan for ANSI C63.19-2011 compliance)/E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 13.63 V/m; Power Drift = 0.29 dB

PMR calibrated. Calibrated PMF = 1.032 is applied.

E-field emissions = 11.91 V/m

Near-field category: M4 (AWF 0 dB)

PMF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
32.82 V/m	18.61 V/m	18.62 V/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
11.84 V/m	11.91 V/m	11.76 V/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
7.183 V/m	9.227 V/m	7.019 V/m

Category	AWF (dB)	Limits for E-Field Emissions (V/m) > 960MHz	Limits for H-Field Emissions (A/m) > 960MHz
M1	0	199.5 - 354.8	0.6 - 1.07

	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.14 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.14

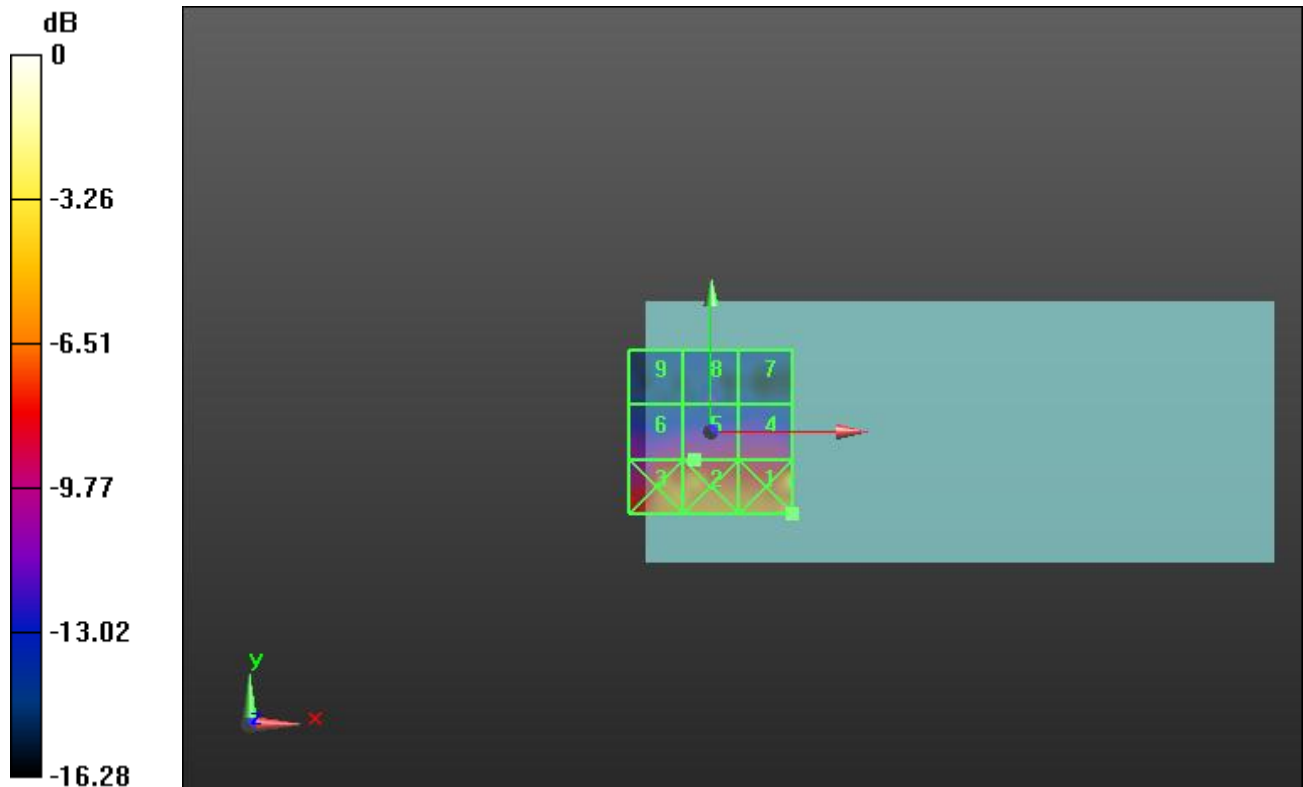
Category	AWF (dB)	Limits for E-Field Emissions (V/m) < 960MHz	Limits for H-Field Emissions (A/m) < 960 MHz
M1	0	631 - 1122	1.91 - 3.39
	-5	473.2 - 841.4	1.43 - 2.54
M2	0	354.8 - 631	1.07 - 1.91
	-5	266.1 - 473.2	0.8 - 1.43
M3	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M4	0	<199.5	<0.6
	-5	<149.6	<0.45

Cursor:

Total = 32.82 V/m

E Category: M4

Location: 25, -25, 8.7 mm



$$0 \text{ dB} = 32.82 \text{ V/m} = 30.32 \text{ dBV/m}$$